

# SSCE24V32N1

Ultra-low Capacitance Bidirectional Micro Packaged TVS Diodes for ESD Protection

## Description

The SSCE24V32N1 is a bi-directional TVS diode, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive high-speed data lines. The SSCE24V32N1 has an ultra-low capacitance with a typical value at 0.3pF, and complies with the IEC 61000-4-2 (ESD) with ±15kV air and ±10kV contact discharge. It is assembled into an ultra-small 1.0x0.6x0.5mm lead-free DFN package.

The small size, ultra-low capacitance and high ESD surge protection make SSCE24V32N1 an ideal choice to protect cell phone and high-power USB.

#### Feature

- ♦ 70W peak pulse power ( $t_P = 8/20\mu s$ )
- ♦ DFN1006-2L Package
- ♦ Working voltage: 24V
- ♦ Low clamping voltage
- ♦ Low capacitance
- ♦ Low leakage current
- Complies with following standards:
  - IEC 61000-4-2 (ESD) immunity test

Air discharge: ±15kV

Contact discharge: ±10kV

- IEC61000-4-5 (Lightning) 1.5A (8/20µs)
- ♦ RoHS compliant

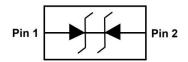
#### Mechanical data

- ♦ Lead finish:100% matte Sn (Tin)
- Case Material: "Green" Molding Compound
- ♦ Qualified max reflow temperature:260 °C
- ♦ Device meets MSL 3 requirements
- ♦ Pure tin plating: 7 ~ 17 um
- ♦ Pin flatness: ≤3mil

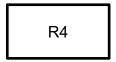
# PIN configuration



DFN1006-2L (Bottom View)



**Circuit Diagram** 



<u>Marking</u>

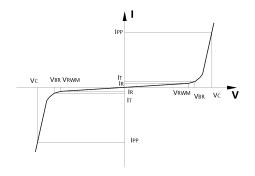
### Applications

- ♦ DVI & HDMI Port Protection
- ♦ USB 2.0 and USB 3.0
- ♦ SATA and eSATA
- ♦ Serial and Parallel Ports
- ♦ Projection TV
- Notebooks, Desktops, Servers



### • Electronic Parameter

Symbol	Parameter	
$V_{RWM}$	Peak Reverse Working Voltage	
I <sub>R</sub>	Reverse Leakage Current @ V <sub>RWM</sub>	
$V_{BR}$	Breakdown Voltage @ I⊤	
I <sub>T</sub>	Test Current	
I <sub>PP</sub>	Maximum Reverse Peak Pulse Current	
Vc	Clamping Voltage @ I <sub>PP</sub>	
P <sub>PP</sub>	Peak Pulse Power	



# Absolute maximum rating @T<sub>A</sub>=25℃

Parameter		Symbol	Value	Unit
Peak Pulse Power (8/20µs)		P <sub>PP</sub>	70	W
Peak Pulse Current (8/20µs)		I <sub>PP</sub>	1.5	А
ESD Rating per IEC61000-4-2:	Contact	\/	±10	kV
	Air	V <sub>ESD</sub>	±15	
Storage Temperature		T <sub>STG</sub>	-55/+150	$^{\circ}$
Operating Temperature	TJ	-55/+125	$^{\circ}$	

# • Electrical Characteristics @T<sub>A</sub>=25℃

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Peak Reverse Working Voltage	$V_{RWM}$				24	V
Breakdown Voltage	$V_{BR}$	I <sub>T</sub> = 1mA	24.5			V
Reverse Leakage Current	I <sub>R</sub>	V <sub>RWM</sub> = 24V			0.2	μΑ
Clamping Voltage	Vc	$I_{PP} = 1A, t_P = 8/20 \mu s$			40	V
Clamping Voltage	Vc	$I_{PP} = 1.5A, t_P = 8/20 \mu s$			45	V
	V <sub>CL-ESD</sub>	IEC 61000-4-2+	60			
ESD Clamping Voltage(Note1)		8kV(I <sub>TLP</sub> =16A),contact				V
ESD Clamping Voltage(Note1)		mode,T=25℃, pin1 to		60		V
		pin2,pin2 to pin1				
Dynamic resistance	$R_{DYN}$			1.5	·	Ω
Junction Capacitance	Сл	V <sub>R</sub> = 0V, f = 1MHz		0.3	0.5	pF

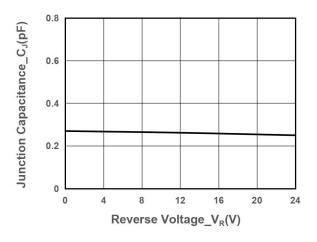
Note 1: ESD Clamping Voltage was measured by Transmission Line Pulsing (TLP) System.

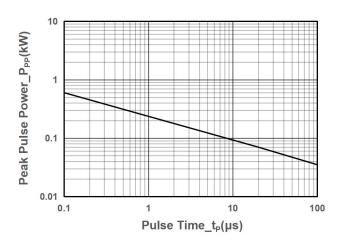
TLP conditions:  $Z_0$ =50  $\Omega$  ,  $t_p$ = 100ns,  $t_r$ = 1ns.

2/5

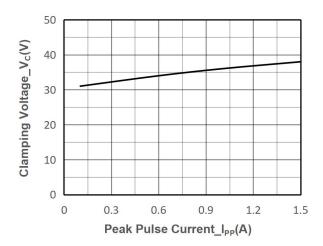


# • Typical Performance Characteristics

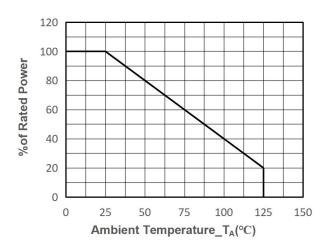




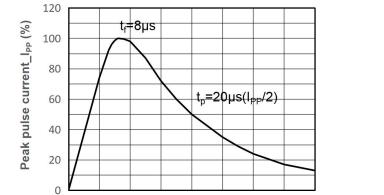
### Junction Capacitance vs. Reverse Voltage



Peak Pulse Power vs. Pulse Time



Clamping Voltage vs. Peak Pulse Current



20

Time\_t(us)

30

Power derating vs. Ambient temperature

8/20µs Pulse Waveform

10

0



# • Package Information

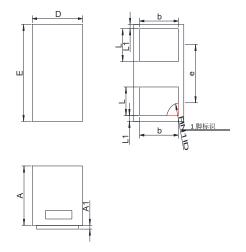
# **Ordering Information**

Device	Package	Qty per Reel	Reel Size
SSCE24V32N1	DFN1006-2L	10000	7 Inch

### **Mechanical Data**

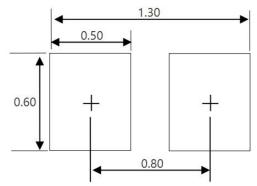
Case: DFN1006-2L

Case Material: Molded Plastic. UL Flammability



DIM	Millimeters			
DIIVI	Min	Max		
Α	0.45	0.55		
<b>A</b> 1	0.00	0.05		
D	0.55	0.65		
E	0.95	1.05		
b	0.45	0.60		
е	0.65TYP			
L	0.2	0.3		
L1	0.05REF			

### **Recommended Pad outline**



Unit:mm



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